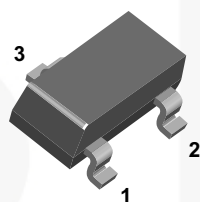




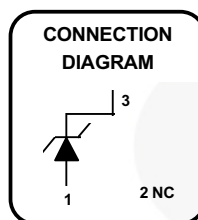
November 2015

BZX84C3V3 - BZX84C33 Zeners

Tolerance: C = 5%



SOT-23



Absolute Maximum Ratings^{(1),(2)}

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

| Symbol | Parameter | | Value | Unit |
|-----------------|---|--|-------------|--------------------|
| I_{FRM} | Repetitive Peak Forward Current | | 250 | mA |
| I_{ZRM} | Repetitive Peak Working Current | | 250 | mA |
| P_D | Power Dissipation | Referencing $R_{\theta JA}$, $T_A = 25^\circ\text{C}$ | 250 | mW |
| | | Referencing ψ_{JL} , $T_L = 25^\circ\text{C}$ | 550 | |
| $R_{\theta JA}$ | Junction-to-Ambient Thermal Resistance ⁽³⁾ | | 465 | $^\circ\text{C/W}$ |
| ψ_{JL} | Junction-to-Lead Thermal Characteristics (with reference to Cathode) | | 220 | $^\circ\text{C/W}$ |
| T_{STG} | Storage Temperature Range | | -55 to +150 | $^\circ\text{C}$ |
| T_J | Operating Junction Temperature | | -55 to +150 | $^\circ\text{C}$ |

Notes:

1. These ratings are based on a maximum junction temperature of 150°C .
2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.
3. Device mounted on FR-4 PCB, board size = 76.2 mm x 114.3 mm

Electrical Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

| Device | Mark | $I_Z = 5.0\text{ mA}$ | | | $I_Z = 1.0\text{ mA}$ | | | $I_Z = 20\text{ mA}$ | | |
|-----------|------|-----------------------|------|------------------------------|-----------------------|------|------------------------------|----------------------|------|------------------------------|
| | | $V_Z\text{ (V)}$ | | $Z_Z\text{ (}\Omega\text{)}$ | $V_Z\text{ (V)}$ | | $Z_Z\text{ (}\Omega\text{)}$ | $V_Z\text{ (V)}$ | | $Z_Z\text{ (}\Omega\text{)}$ |
| | | Min. | Max. | | Min. | Max. | | Min. | Max. | |
| BZX84C3V3 | Z14 | 3.1 | 3.5 | 95 | 2.3 | 2.9 | 600 | 3.6 | 4.2 | 40 |
| BZX84C3V6 | Z15 | 3.4 | 3.8 | 90 | 2.7 | 3.3 | 600 | 3.9 | 4.5 | 40 |
| BZX84C3V9 | Z16 | 3.7 | 4.1 | 90 | 2.9 | 3.5 | 600 | 4.1 | 4.7 | 30 |
| BZX84C4V3 | Z17 | 4.0 | 4.6 | 90 | 3.3 | 4.0 | 600 | 4.4 | 5.1 | 30 |
| BZX84C4V7 | Z1 | 4.4 | 5.0 | 80 | 3.7 | 4.7 | 500 | 4.5 | 5.4 | 15 |
| BZX84C5V1 | Z2 | 4.8 | 5.4 | 60 | 4.2 | 5.3 | 480 | 5.0 | 5.9 | 15 |
| BZX84C5V6 | Z3 | 5.2 | 6.0 | 40 | 4.8 | 6.0 | 400 | 5.2 | 6.3 | 10 |
| BZX84C6V2 | Z4 | 5.8 | 6.6 | 10 | 5.6 | 6.6 | 150 | 5.8 | 6.8 | 6 |
| BZX84C6V8 | Z5 | 6.4 | 7.2 | 15 | 6.3 | 7.2 | 80 | 6.4 | 7.4 | 6 |
| BZX84C7V5 | Z6 | 7.0 | 7.9 | 15 | 6.9 | 7.9 | 80 | 7.0 | 8.0 | 6 |
| BZX84C8V2 | Z7 | 7.7 | 8.7 | 15 | 7.6 | 8.7 | 80 | 7.7 | 8.8 | 6 |
| BZX84C9V1 | Z8 | 8.5 | 9.6 | 15 | 8.4 | 9.6 | 100 | 8.5 | 9.7 | 8 |
| BZX84C10 | Z9 | 9.4 | 10.6 | 20 | 9.3 | 10.6 | 150 | 9.4 | 10.7 | 10 |
| BZX84C11 | Y1 | 10.4 | 11.6 | 20 | 10.2 | 11.6 | 150 | 10.4 | 11.8 | 10 |
| BZX84C12 | Y2 | 11.4 | 12.7 | 25 | 11.2 | 12.7 | 150 | 11.4 | 12.9 | 10 |
| BZX84C13 | Y3 | 12.4 | 14.1 | 30 | 12.3 | 14.0 | 170 | 12.5 | 14.2 | 15 |
| BZX84C15 | Y4 | 13.8 | 15.6 | 30 | 13.7 | 15.5 | 200 | 13.9 | 15.7 | 20 |
| BZX84C16 | Y5 | 15.3 | 17.1 | 40 | 15.2 | 17.0 | 200 | 15.4 | 17.2 | 20 |
| BZX84C18 | Y6 | 16.8 | 19.1 | 45 | 16.7 | 19.0 | 225 | 16.9 | 19.2 | 20 |
| BZX84C20 | Y7 | 18.8 | 21.2 | 55 | 18.7 | 21.1 | 225 | 18.9 | 21.4 | 20 |
| BZX84C22 | Y8 | 20.8 | 23.3 | 55 | 20.7 | 23.2 | 250 | 20.9 | 23.4 | 25 |
| BZX84C24 | Y9 | 22.8 | 25.6 | 70 | 22.7 | 25.5 | 250 | 22.9 | 25.7 | 25 |
| BZX84C27 | Y10 | 25.1 | 28.9 | 80 | 25.0 | 28.9 | 300 | 25.2 | 29.3 | 45 |
| BZX84C30 | Y11 | 28.0 | 32.0 | 80 | 27.8 | 32.0 | 300 | 28.1 | 32.4 | 50 |
| BZX84C33 | Y12 | 31.0 | 35.0 | 80 | 30.8 | 35.0 | 325 | 31.1 | 35.4 | 55 |

V_F Forward Voltage = 0.9 V Maximum at $I_F = 10\text{ mA}$ for all BZX84 series

Electrical Characteristics (Continued)Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

| Device | V_R (V) | I_R (μA) | Cap ⁽⁴⁾ (pF) | D_{VZ} / D_t at 5.0 mA (mV/k) | |
|-----------|-----------|-------------------------|-------------------------|---------------------------------|------|
| | | | | Min. | Max. |
| BZX84C3V3 | 1.0 | 5.0 | 450 | -3.5 | 0.0 |
| BZX84C3V6 | 1.0 | 5.0 | 450 | -3.5 | 0.0 |
| BZX84C3V9 | 1.0 | 5.0 | 450 | -3.5 | 0.0 |
| BZX84C4V3 | 1.0 | 5.0 | 450 | -3.5 | 0.0 |
| BZX84C4V7 | 2.0 | 3 | 260 | -3.5 | 0.2 |
| BZX84C5V1 | 2.0 | 2 | 225 | -2.7 | 1.2 |
| BZX84C5V6 | 2.0 | 1 | 200 | -2.0 | 2.5 |
| BZX84C6V2 | 4.0 | 3 | 185 | 0.4 | 3.7 |
| BZX84C6V8 | 4.0 | 2 | 155 | 1.2 | 4.5 |
| BZX84C7V5 | 5.0 | 1 | 140 | 2.5 | 5.3 |
| BZX84C8V2 | 5.0 | 0.7 | 135 | 3.2 | 6.2 |
| BZX84C9V1 | 6.0 | 0.5 | 130 | 3.8 | 7.0 |
| BZX84C10 | 7.0 | 0.2 | 130 | 4.5 | 8.0 |
| BZX84C11 | 8.0 | 0.1 | 130 | 5.4 | 9.0 |
| BZX84C12 | 8.0 | 0.1 | 130 | 6.0 | 10 |
| BZX84C13 | 8.0 | 0.1 | 120 | 7.0 | 11 |
| BZX84C15 | 10.5 | 0.05 | 110 | 9.2 | 13 |
| BZX84C16 | 11.2 | 0.05 | 105 | 10.4 | 14 |
| BZX84C18 | 12.6 | 0.05 | 100 | 12.4 | 16 |
| BZX84C20 | 14 | 0.05 | 85 | 14.4 | 18 |
| BZX84C22 | 15.4 | 0.05 | 85 | 16.4 | 20 |
| BZX84C24 | 16.8 | 0.05 | 80 | 18.4 | 22 |
| BZX84C27 | 18.9 | 0.05 | 70 | 21.4 | 25.3 |
| BZX84C30 | 21 | 0.05 | 70 | 24.4 | 29.4 |
| BZX84C33 | 23.1 | 0.05 | 70 | 27.4 | 33.4 |

Note:4. Capacitance at $V_R = 0.0$ V, $f = 1.0$ MHz.

Typical Performance Characteristics

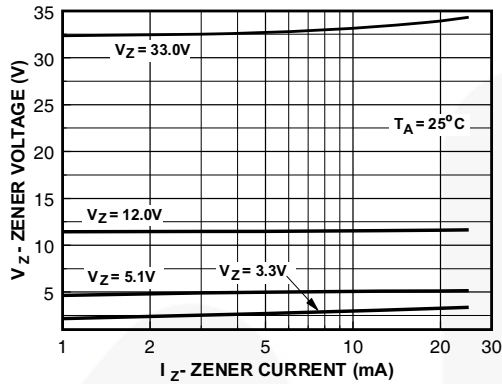


Figure 1. Zener Current vs. Zener Voltage

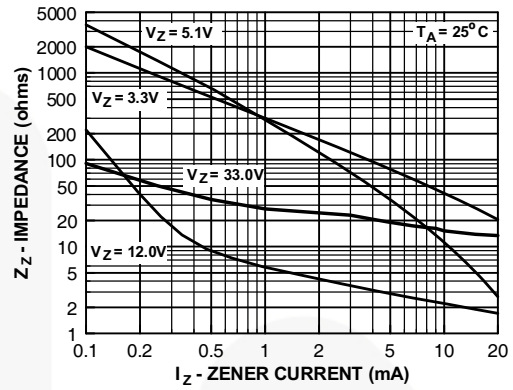


Figure 2. Zener Current vs. Zener Impedance

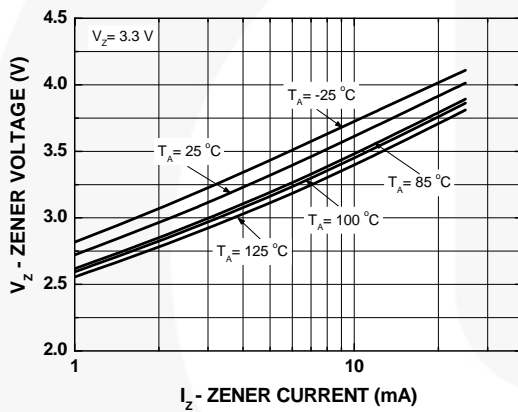


Figure 3. 3.3 V Zener Voltage vs. Temperature

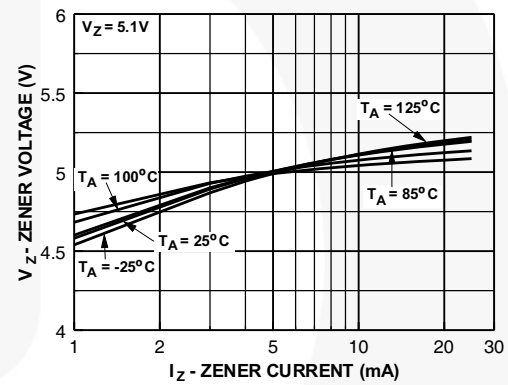


Figure 4. 5.1 V Zener Voltage vs. Temperature

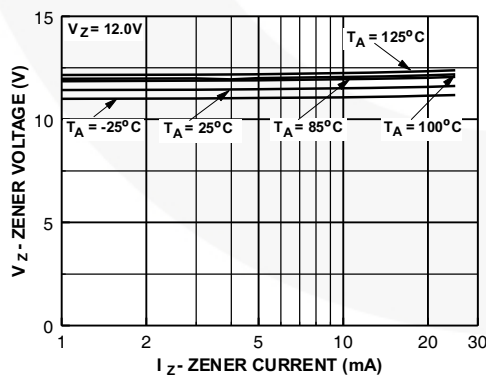


Figure 5. 12 V Zener Voltage vs. Zener Temperature

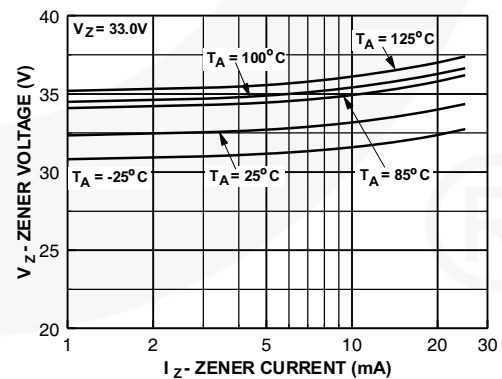
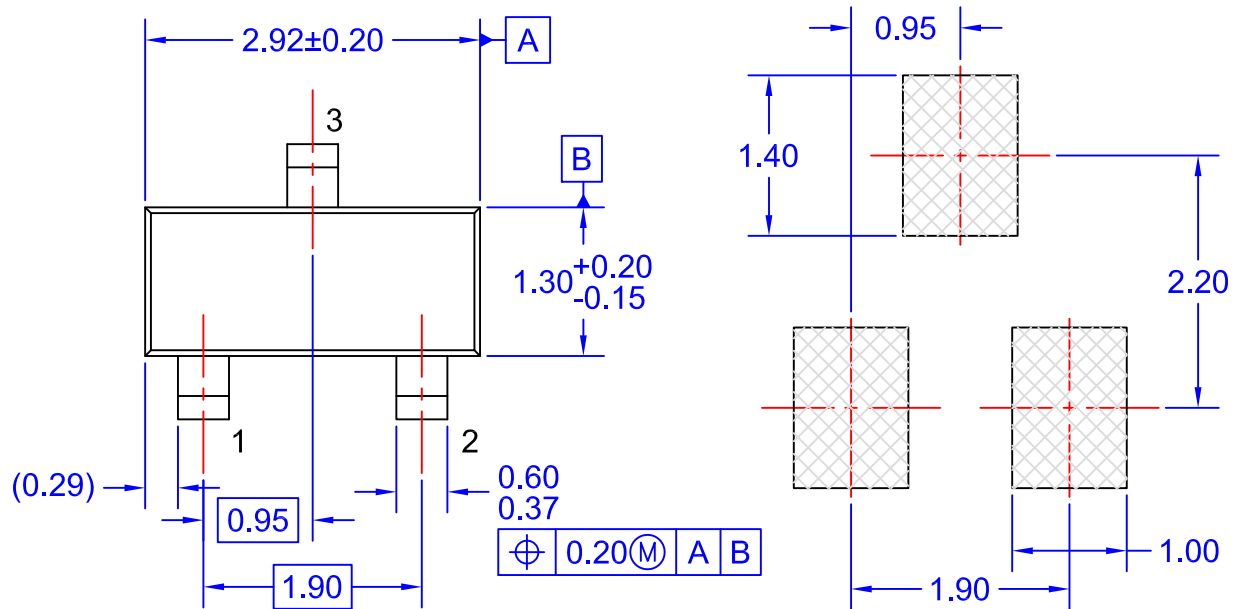
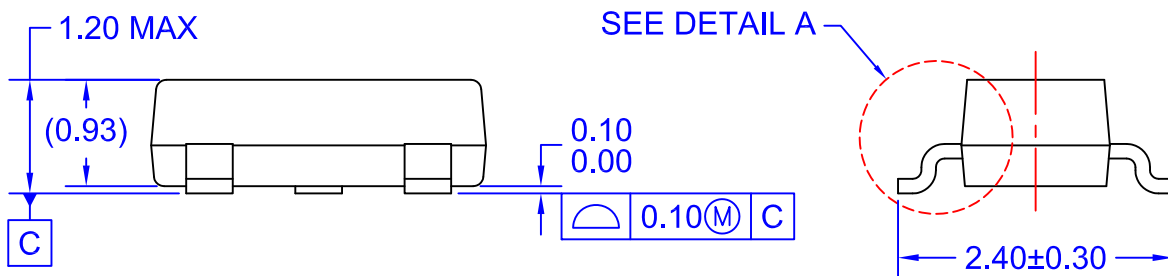


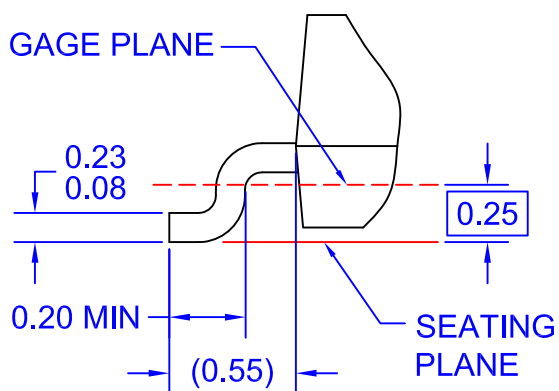
Figure 6. 33 V Zener Voltage vs. Zener Temperature



LAND PATTERN
RECOMMENDATION



NOTES: UNLESS OTHERWISE SPECIFIED



DETAIL A
SCALE: 2X

- A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
- D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 2009.
- E) DRAWING FILE NAME: MA03DREV12



ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada

Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910

Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local
Sales Representative